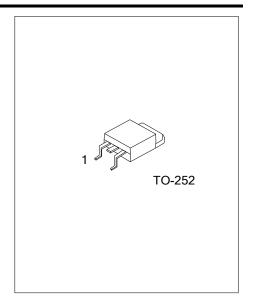
HJ45H11

PNP SILICON TRANSISTOR

PNP EPITAXIAL PLANAR TRANSISTOR

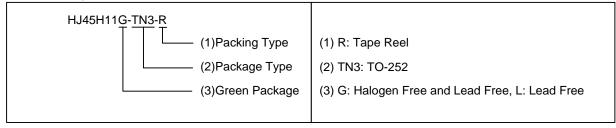
DESCRIPTION

The **HJ45H11** is designed for various specific and general purpose applications, such as: output and driver stages of amplifiers operating at frequencies from DC to greater than 1MHz; series, shunt and switching regulators; low and high frequency inverters/converters; and many others.

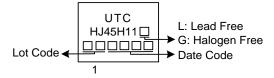


■ ORDERING INFORMATION

Ordering Number		Daakana	Pin Assignment			Dealine	
Lead Free	Halogen Free	Package	1	2	3	Packing	
HJ45H11L-TN3-R	HJ45H11G-TN3-R	TO-252	В	С	Е	Tape Reel	



■ MARKING



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector- Emitter Voltage	V_{CEO}	-80	V
Collector-Emitter Voltage	$V_{\sf CES}$	-80	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	Ic	-10	Α
Base Current	I_{B}	-5	Α
Power Dissipation (T _C =25°C)	P_D	20	W
Junction Temperature	T_J	+150	°C
Storage Temperature	T _{STG}	-55 ~ + 150	°C

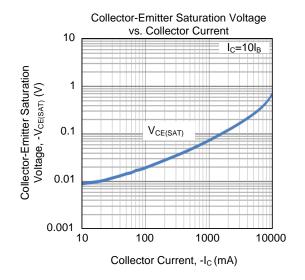
Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

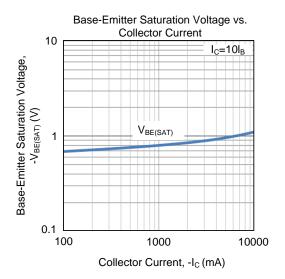
■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

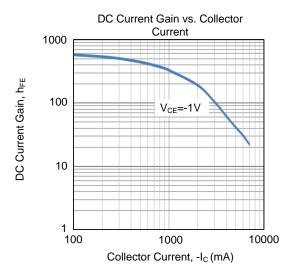
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =-30mA, I _B =0	-80			V
Collector-Emitter Breakdown Voltage	BV _{CES}	$I_C=-1$ mA, $I_B=0$	-80			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =-1mA, I _C =0	-5			V
Collector Cut-Off Current	I _{CBO}	V _{CB} =-80V, V _{EB} =0			-10	uA
Emitter Cut-off Current	I _{EBO}	V_{EB} =-5 V , I_{C} =0			-50	uA
Collector-Emitter Saturation Voltage(Note)	V _{CE(SAT)}	I_{C} =-8A, I_{B} =-0.8A			-1	V
Base-Emitter Saturation Voltage(Note)		I_{C} =-8A, I_{B} =-0.8A			-1.5	V
DO Comment Onlin (Note)	h _{FE1}	V _{CE} =-1V, I _C =-2A	60			
DC Current Gain (Note)	h _{FE2}	V _{CE} =-1V, I _C =-4A	40			
Output Capacitance	Сов	V _{CB} =-10V		120		pF

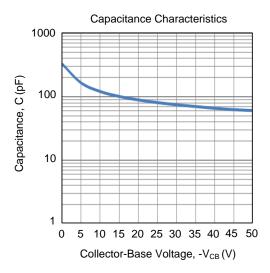
Note: Pulse Test: Pulse Width ≤ 380us, Duty Cycle ≤ 2%.

■ TYPICAL CHARACTERISTICS









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